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STATEMENT BY APPLICANT**  
( Not for submission under 37 CFR 1.99)

Application Number	10696545
Filing Date	2003-10-29
First Named Inventor	Xunming Deng
Art Unit	1795
Examiner Name	Jeffrey Thomas Barton
Attorney Docket Number	1-25574

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	3	6242686		2001-06-05	KISHIMOTO et al.	
	4	6361660		2002-03-26	GOLDSTEIN	
	5	6471850		2002-10-29	SHIEPE et al.	
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/JB/	1	Miller, E.L.; Rocheleau, R.E., Deng, X.M., Design considerations for a hybrid amorphous silicon/photovoltaic multi-junction cell for hydrogen production, Int. J. Hydrogen Energy, 28(6), 2003, 615-623.	<input type="checkbox"/>

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/JB/	2	Bak, T.; Nowotny, J.; Rekas, M.; Sorrell, C.C., Photo-electrochemical hydrogen generation from water using solar energy, Materials-related aspects, Int. J. Hydrogen Energy, 27 (10), 2002, 991-1022.	<input type="checkbox"/>
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	10	Kocha, S.S., Montgomery, D., Peterson, M.W. , Turner, JA, Photoelectrochemical decomposition of water utilizing monolithic tandem cells, Solar Energy Materials & Solar Cells, 52, 389-397 (1998).	<input type="checkbox"/>
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	15	Perez-Mendez, V., Morel, J., Kaplan, S. N. , Street, R. A., Detection of Charged Particles in Amorphous Silicon Layers, Nuclear Instruments and Methods in Physics Research, 252, 478-482 (1986). <input type="checkbox"/>
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Examiner Signature	/Jeffrey Barton/	Date Considered	08/27/2009
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